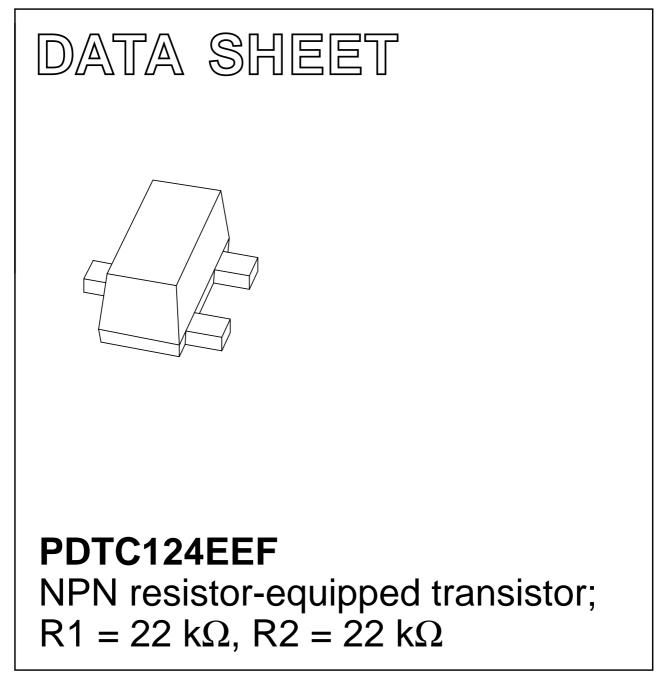
DISCRETE SEMICONDUCTORS



Product specification

2002 Mar 14



PDTC124EEF

NPN resistor-equipped transistor; R1 = 22 k Ω , R2 = 22 k Ω

FEATURES

- Built-in bias resistors
- 250 mW total power dissipation
- + Very small $1.6 \times 0.85 \times 0.7$ mm package
- Flat leads
- Excellent coplanarity
- Improved thermal behaviour
- Reduces number of components and required PCB area.

APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Driver circuits.

DESCRIPTION

NPN resistor-equipped transistor in a SOT490 (SC-89) plastic package.

MARKING

TYPE NUMBER	MARKING CODE		
PDTC124EEF	36		

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT	
V _{CEO}	collector-emitter voltage	50	V	
I _O	output current (DC)	100	mA	
R1	bias resistor	22	kΩ	
R2	bias resistor	22	kΩ	

PINNING

PIN	DESCRIPTION	
1	base/input	
2	emitter/ground (+)	
3	collector/output	

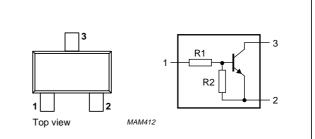
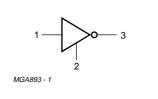
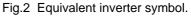


Fig.1 Simplified outline (SOT490) and symbol.





PDTC124EEF

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	10	V
Vi	input voltage				
	positive		-	+40	V
	negative		-	-10	V
I _O	output current (DC)		-	100	mA
I _{CM}	peak collector current		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$; note 1	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. For mounting conditions, see "Thermal considerations and footprint design for SOT490 in the SC18 Data Handbook".

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R _{th j-a}	thermal resistance from junction to ambient	in free air; note 1	500	K/W	

Note

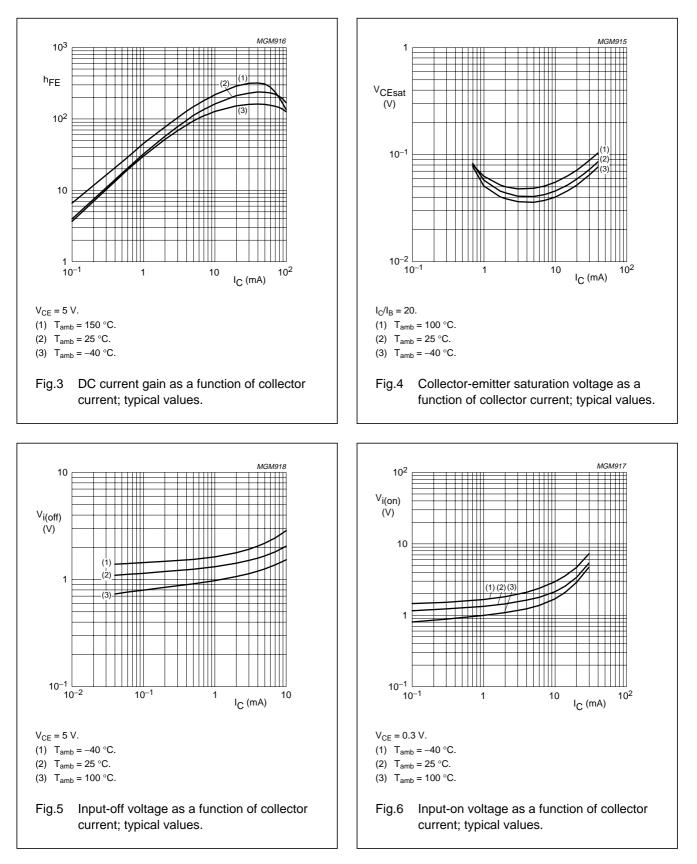
1. For mounting conditions, see "Thermal considerations and footprint design for SOT490 in the SC18 Data Handbook".

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0$	-	-	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0$	-	-	1	μA
		$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	-	50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0$	-	-	180	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; \text{ I}_{C} = 5 \text{ mA}$	60	-	_	
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA	-	-	150	mV
V _{i(off)}	input off voltage	$V_{CE} = 5 \text{ V}; \text{ I}_{C} = 100 \mu\text{A}$	-	1.1	0.8	V
V _{i(on)}	input on voltage	V _{CE} = 0.3 V; I _C = 5 mA	2.5	1.7	_	V
R1	input resistor		15.4	22	28.6	kΩ
R2 R1	resistor ratio		0.8	1	1.2	
C _c	collector capacitance	$I_E = i_e = 0; V_{CB} = 10 V;$ f = 1 MHz	-	-	2.5	pF

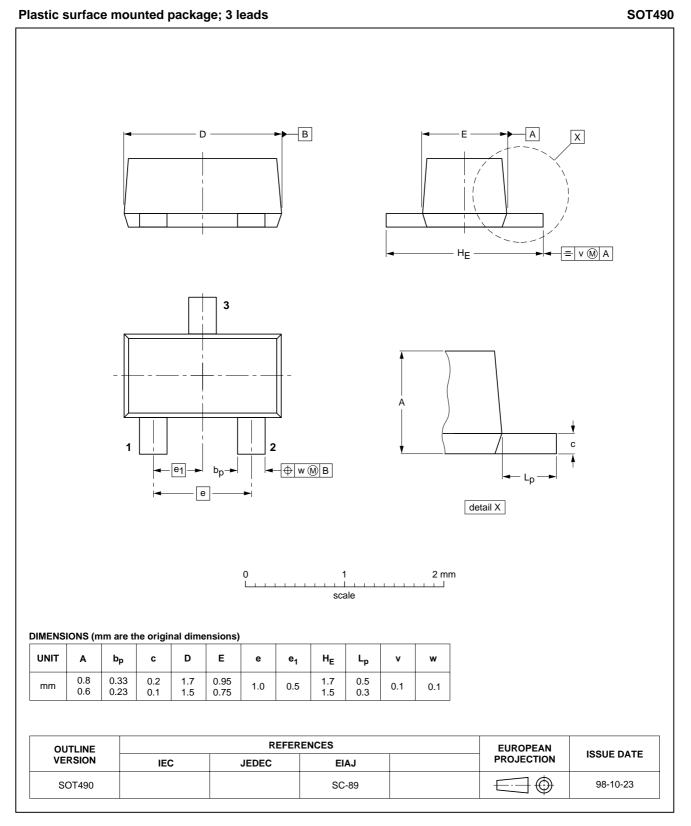
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PACKAGE OUTLINE



PDTC124EEF

DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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